

Features:

- Standard miniature surface mount footprint
- Frequency range 1.5 to 125 MHz
- Frequency stability: 100 ppm standard; 50 ppm and 25 ppm available
- Low voltage option available
- CMOS/TTL compatible
- Tri-State Output standard
- Tape and reel packaging (16mm)
- PCMCIA Type II & III compatible
- Fibre Channel Compliant
- Gigabit Ethernet Compliant



The CTS CB3 is a ceramic packaged Clock oscillator offering reduced size and enhanced stability. The small size means it is perfect for any application. The enhanced stability means it is the perfect choice for today's communications applications that require tight frequency control. Low voltage options are also available. Tristate control is also standard.

Specifications:

PARAMETER	SYMBOL	CONDITIONS	MINIMUM	TYPICAL	MAXIMUM	UNITS
Frequency Range	F		1.5		125	MHz
Stability	$\Delta F/F$	Note 1			25, 50, or 100	ppm
Operating Temp.	T _A	Commercial Industrial	0 -40		+70 +85	°C
Supply Voltage	V _{CC}	Operating Voltage Options	4.5 3.0	5.0 3.3	5.5 3.6	V
Supply Current	I _{CC}	≤20.0 MHz >20.0 MHz to ≤80MHz >80 MHz to 125MHz 5.0 Volt Supply 3.3 Volt Supply 5.0 Volt Supply 3.3 Volt Supply 5.0 Volt Supply 3.3 Volt Supply			25 12 50 40 100 60	mA
Output Load		1.5 MHz to 50.0 MHz 50.1MHz to 80.0 MHz			50 30	pF
Output Voltage Level	V _{OH}	CMOS Load TTL Load	V _{CC} -0.5V V _{CC} -0.6V			V
	V _{OL}	CMOS or TTL Load			0.4	V
Output Current	I _{OH}	V _{OH} = 3.9V/2.2V V _{DD} =4.5V/3.0V			+16/+8	mA
	I _{OL}	V _{OL} = 0.4V V _{DD} =4.5V/3.0V			-16/-8	mA
Symmetry	Duty	1.5 MHz to 60.0 MHz 60.1 MHz to 125 MHz	45 40		55 60	%
Rise & Fall Time	T _r , T _f	≤20.0 MHz >20.0 MHz to <50.0 MHz 50.0 MHz to 80.0 MHz >80 MHz to 125MHz			10 8 5 4	ns
Enable Input Voltage(or NC)	V _{IH}		2.0			V
Disable Input Voltage	V _{IL}				0.8	V
Tristate Leakage Current	I _Z	V _{IL} = 0.8V			0.05	mA

Note 1: Inclusive of initial tolerance at time of shipment, changes in supply voltage, load, temperature, and first year aging at an average operating temperature of 40 °C

Test Conditions

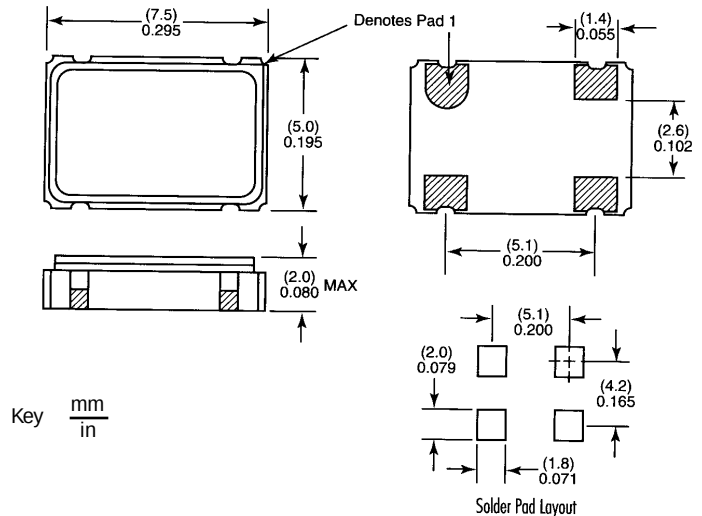
Symmetry	50% of waveform
Load	per above table
Rise & Fall Time	10%—90% of waveform

Pad Connections

PAD	FUNCTION
1	Output Enable
2	Cover/CKT GND
3	Output
4	Vcc

Tristate Truth Table

Pin 1 (Enable)	Pin 3 (Output)
Floating (No Connect)	Enabled (Oscillating)
Logic 1	Enabled (Oscillating)
Logic 0	Disabled (Tristate)



Environmental Characteristics:

Storage Temperature: -55°C to +125°C
 Temperature Cycle: 25 cycles, -55°C to +125°C
 per MIL-STD-883, Method 1010
 Mechanical Shock 1500g's, 0.5mS,
 3 shocks per direction,
 per MIL-STD-883, Method 2002
 Sinusoidal Vibration: 0.06" D.A., 10 to 55 Hz and
 30g's, 55 to 2000 Hz,
 3 cycles per direction,
 per MIL-STD-883, Method 2007
 Random Vibration: 20G^{RMS}, 20 to 2000 Hz,
 per MIL-STD-883, Method 2026
 Lead Integrity: per MIL-STD-883,
 Method 2004 conditions B1 and B2
 Hermeticity: 3 x 10⁴ ATM-cc/sec,
 per MIL-STD-883,
 Method 1014 conditions B1 and B2
 Moisture Resistance: 10 cycles, per MIL-STD-883,
 Method 1014 with step 7 subcycle omitted

Corrosion Resistance: 24 hours, per MIL-STD-883,
 Method 1009 condition A
 Solderability: per MIL-STD-883,
 Method 2003 or MIL-STD-202,
 Method 208. Except 1 hr. Pre-conditioning
 Quality: In accordance with MIL-1-45208
 Resistance to Soldering Heat: per MIL-STD-202,
 Method 210 conditions A and C
 Marking Permanence: per MIL-STD-883, Method 2015
 Thermal Resistance: per MIL-STD-883, Method 1012.1
 Electrostatic Discharge Sensitivity: per MIL-STD-883,
 Method 3015 ECL output models-> 4KV
 (Class 2- not sensitive)
 CMOS output models-> 2KV
 (Class 1 - not sensitive)
 Steady-State Life: ... 1000 hrs. @ 125°C per MIL-STD-883,
 Method 1005, disregarding frequency shift
 Frequency Aging: <10 ppm shift in 30 days
 @ 85°C ambient

Configuring The Part Number...

CB3 - - -

Blank = 5.0V
 LV = 3.3 Volt

2 = ±100 ppm
 3 = ±50 ppm
 5 = ±25 ppm

C = 0 to 70°C
 I = -40 to 85°C

Frequency
 (MHz)